## NSN 5961-01-046-9558

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-046-9558

view offilite at https://aerobasegroup.com/nsn/0501-01-040-5550
Inclosure Material:
Metal
Overall Length:
1.252 inches
Overall Height:
0.340 inches
Overall Width:
0.700 inches
Mounting Facility Quantity:
2
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-66
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Unthreaded hole
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
250.0 collector to base voltage/static/emitter open and 200.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
Between 500.00 milliamperes source cutoff current and 2.00 amperes source cutoff current
Power Rating Per Characteristic:
20.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Precious Material And Location:
Terminal surface option gold
Precious Material:
Gold
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
2 uninsulated wire lead and 1 case

Shelf Life:

**Specification Data:** 

81349-mil-s-19500/454 government specification

## NSN 5961-01-046-9558

Transistor - Page 2 of 2



			ure:	

--

Demilitarization:

No

Fiig:

A110a0